

DATASHEET

1.9mm Round Subminiature "Gull Wing" Lead **Phototransistor**

PT91-21B/TR7(XY)



Features

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Compatible with infrared and vapor phase reflow solder process.
- Pb free
- The product itself will remain within RoHS compliant version.
- Compliance with EU REACH.
- Compliance Halogen Free .(Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm).

Descriptions

• PT91-21B/TR7(XY) is a phototransistor in miniature SMD package which is molded in black plastic with spherical top view lens. The device is spectrally matched to infrared emitting diode.

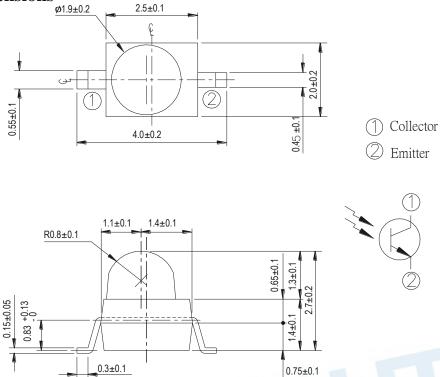
Applications

- Miniature switch
- Counters and sorter
- Position sensor
- Infrared applied system

Device Selection Guide

Part Category	Chip Material	Lens Color	
PT	Silicon	Black	





Notes: 1.All dimensions are in millimeters

2. Tolerances unless dimensions ±0.1mm

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Collector-Voltage	V _{ECO}	5	V
Collector Current	I_{C}	20	mA
Operating Temperature	Topr	-25 ~ +85	$^{\circ}\!\mathbb{C}$
Storage Temperature	T_{stg}	-40 ~ +85	$^{\circ}\!\mathbb{C}$
Soldering Temperature *1	T_{sol}	260	$^{\circ}\!\mathbb{C}$
Power Dissipation at(or below) 25°C Free Air Temperature	P _d	75	mW

Notes: *1:Soldering time ≤ 5 seconds.

Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Rang Of Spectral Bandwidth	λρ0.5		730		1100	nm
Wavelength Of Peak Sensitivity	$\lambda_{ m P}$			940		nm
Collector-Emitter Breakdown Voltage	BV _{CEO}	I_{C} =100 μ A Ee=0mW/cm ²	30			V
Emitter-Collector Breakdown Voltage	$\mathrm{BV}_{\mathrm{ECO}}$	$I_E=10\mu A$ $Ee=0mW/cm^2$	5			V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =2mA Ee=1mW/cm ²			0.4	V
Collector Dark Current	I _{CEO}	V _{CE} =20V Ee=0mW/cm ²			100	nA
On State Collector Current	I _{C(ON)}	V _{CE} =5V Ee=1mW/cm ²	1.5		6.0	mA

Bin Range of Reverse Light Current

Bin Code	Min.	Max.	Unit	Condition
BIN2	1.50	3.00		
BIN3	2.00	4.00	mA	$V_{CE}=5V$
BIN4	2.50	5.00		Ee=1mW/cm ²
BIN5	3.00	6.00		

Notes: 1. Tolerance of Luminous Intensity: ±17%

Typical Electro-Optical Characteristics Curves

Fig.1 Spectral Sensitivity

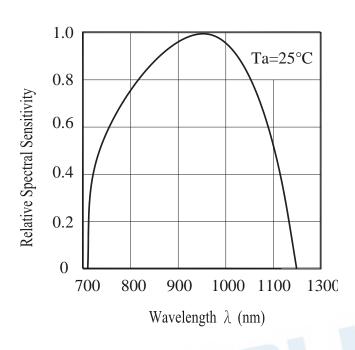


Fig.2 Collector Current vs.

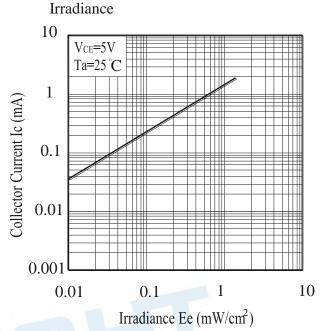
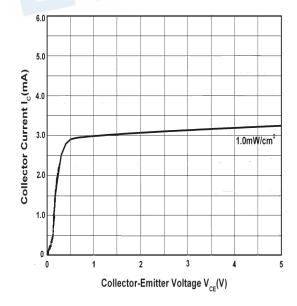


Fig.3 Collector Current vs.

Collector-Emitter Voltage



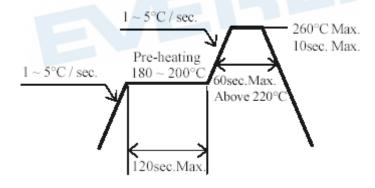
Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

- 2. Storage
 - 2.1 Do not open moisture proof bag before the products are ready to use.
 - 2.2 Before opening the package, the Phototransistor should be kept at 30° C or less and 90%RH or less.
 - 2.3 The Phototransistor should be used within a year.
- 2.4 After opening the package, the Phototransistor should be kept at 30°C or less and 70%RH or less.
- 2.5 The Phototransistor should be used within 168 hours (7 days) after opening the package.
- 2.6 If the moisture absorbent material (silica gel) has faded away or the Phototransistor have exceeded the storage time, baking treatment should be performed using the following conditions.

 Baking treatment: 60±5°C for 24 hours.
- 3. Soldering Condition
- 3.1 Pb-free solder temperature profile



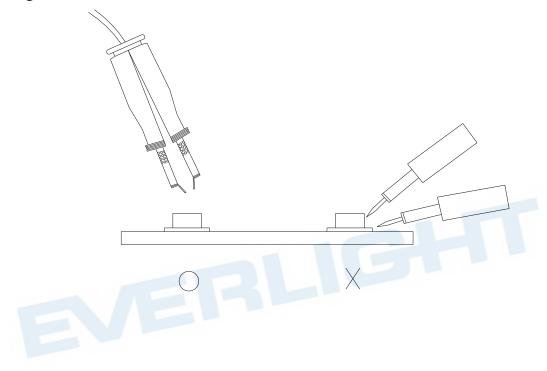
- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the Phototransistor during heating.
- 3.4 After soldering, do not warp the circuit board.
- 4. Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 350°C for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more

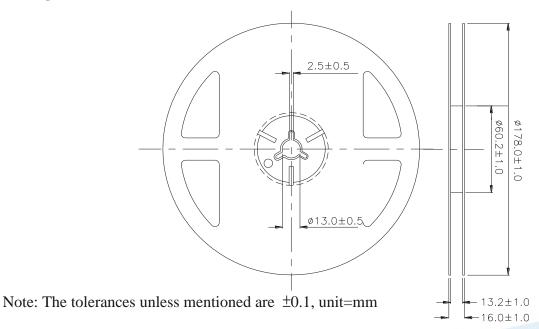
intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

5.Repairing

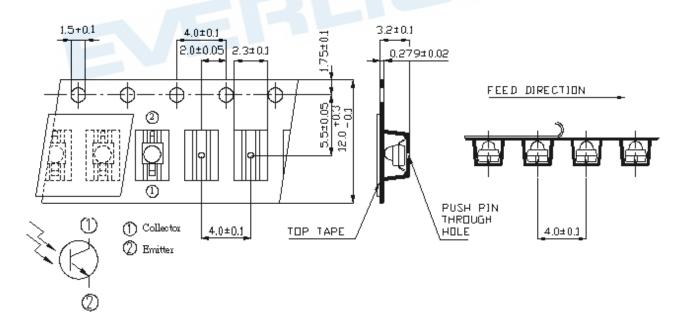
Repair should not be done after the Phototransistor have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the Phototransistor will or will not be damaged by repairing.



Package Dimensions



Carrier Taping Dimensions: (Quantity: 1000PCS/Reel)



Note: The tolerances unless mentioned are ± 0.1 , unit=mm

Label Form Specification



CPN: Customer's Production Number

P/N: Production Number **QTY:** Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

DISCLAIMER

- EVERLIGHT reserves the right(s) on the adjustment of product material mix for the 1. specification.
- The product meets EVERLIGHT published specification for a period of twelve (12) months 2. from date of shipment.
- 3. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- When using this product, please observe the absolute maximum ratings and the instructions for 4. using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from the use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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